

L Number	Hits	Search Text	DB	Time stamp
1	120	((conduct\$4 near10 amorphous) near10 resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:08
2	12206	(conduct\$4 near10 amorphous)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:09
3	7905	(conduct\$4 near10 (amorphous or diamond-like)) near10 (conduct\$4 resist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:10
7	1431	((conduct\$4 near10 (amorphous or diamond-like)) near10 (conduct\$4 resist))and resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:13
8	285	((conduct\$4 near10 (amorphous or diamond-like)) near10 (conduct\$4 resist))and resistivity and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:13
9	65	((conduct\$4 near10 (amorphous or diamond-like)) near10 (conduct\$4 resist))and resistivity and (liquid adj crystal) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:19
11	3	(conduct\$4 near10 (amorphous or diamond-like) near10 (conduct\$4 resist\$4)near10 resistivity)and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:21
10	86	(conduct\$4 near10 (amorphous or diamond-like) near10 (conduct\$4 resist\$4)near10 resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:38
12	20021	(patiall\$4 or conduct\$4)near10 resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:39
13	954	((patiall\$4 or conduct\$4)near10 resistivity) and passivation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:39
14	0	((patiall\$4 or conduct\$4)near10 resistivity) and passivation and alignmt	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:40
15	396	((patiall\$4 or conduct\$4)near10 resistivity) and passivation and amorphous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:40
16	229	((patiall\$4 or conduct\$4)near10 resistivity) and passivation and amorphous and align\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:49
17	0	((patiall\$4 or conduct\$4)near10 resistivity) near10 passivation and amorphous and align\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:43

18	0	((patiall\$4 or conduct\$4)nearl0 resistivity) nearl0 passivation and amorphous and align\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:45
19	1	amorphous nearl0 resistivity nearl0 passivation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:58
20	1515	amorphous nearl0 resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 13:59
22	34	(amorphous nearl0 resistivity) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 14:24
23	2253975	(amorphous nearl0 resistivity) anearl0 conduct\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 14:25
24	122	(amorphous nearl0 resistivity) nearl0 conduct\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 14:25
-	479	349/113	USPAT	2002/02/06 12:09
-	635	349/139	USPAT	2002/02/05 08:58
-	175	349/147	USPAT	2002/02/05 08:58
-	0	(liquid adj crystal) and ((amorphous same passivat\$) same elctrode) and flicker	USPAT	2002/02/05 09:08
-	280	349/139 and amorphous	USPAT	2004/01/07 16:46
-	25	(liquid adj crystal) and (amorphous same passivat\$) and flicker	USPAT	2002/02/05 11:35
-	2	349/113 and amorphous and flicker	USPAT	2002/02/05 10:22
-	998	(liquid adj crystal) and reflect\$ and flicker	USPAT	2002/02/05 10:24
-	44	(liquid adj crystal) and reflect\$ and flicker and passivation	USPAT	2002/02/05 10:25
-	5	("4470669" "4761058" "5075796" "5115336" "5157541").PN.	USPAT	2002/02/05 10:28
-	14	349/147 and (amorphous same passivation)	USPAT	2002/02/05 11:05
-	102	349/113 and amorphous	USPAT	2004/07/12 10:31
-	28	349/139 and (amorphous same passivation)	USPAT	2002/02/05 14:26
-	42	349/113 and ((Silicon adj oxide) and polyimide)	USPAT	2002/02/05 18:24
-	45	349/113 and ((Silicon adj oxide)or SiO2) and polyimide	USPAT	2002/02/05 18:41
-	2	"L45" same (align\$ or passivation)	USPAT	2002/02/05 18:43
-	0	(349/113 and (align\$ same ((silicon adj oxide) or SiO2))) same passivat\$	USPAT	2002/02/06 09:12
-	9	(349/113 and (align\$ same ((silicon adj oxide) or SiO2)))	USPAT	2002/02/06 09:12
-	9	349/113 and (((silicon adj oxide)or SiO2) same align\$)	USPAT	2002/02/06 12:11
-	86	349/139 and amorphous and resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 20:57
-	1	6532053.pn.	USPAT	2004/01/07 20:50
-	9419	conductive and amorphous and resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 20:57

-	1407	amorphous near10 resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/07 20:59
-	174	(amorphous near10 resistivity) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 15:48
-	25	(conduct\$4 near10 amorphous near10 resistivity) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/16 09:27
-	3	927580.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:24
-	0	09927580.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:25
-	3	9927580.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:35
-	13	(conductive adj color adj filter)and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:36
-	23	(conduct\$4 adj color adj filter)and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:37
-	4	(conduct\$4 adj color adj filter)and 349/\$.ccls. and amorphous	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:52
-	8	(conduct\$4 adj amorphous)and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:54
-	0	((conduct\$4 adj amorphous)near10 resistivity)and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:55
-	0	((conduct\$4 adj amorphous) near20 resistivity)and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:56
-	2	((conduct\$4 adj amorphous) near10 resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/09 16:56
-	102	(conduct\$4 adj amorphous)and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 10:29

-	382	(conduct\$4 adj amorphous)and resist\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 09:48
-	8	(conduct\$4 adj amorphous)and resist\$4 and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 09:50
-	0	((conduct\$4 adj amorphous)near10 resisttivity) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 09:51
-	0	((conduct\$4 adj amorphous)near10 resistivity) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 09:51
-	2	((conduct\$4 adj amorphous) near10 resistivity)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 09:51
-	0	((conduct\$4 adj amorphous)near10 resistivity)and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/10 10:28
-	2	conduct\$4 adj amorphous)near10(resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/13 10:53
-	1488	(conduct\$4 near10 amorphous) and resistivity	USPAT	2004/07/12 10:32
-	0	349/113 and (conduct\$4 near10 amorphous) near10 resistivity	USPAT	2004/07/12 10:34
-	7	349/113 and (conduct\$4 near10 amorphous) and resistivity	USPAT	2004/07/12 10:34
-	68	(conduct\$4 near10 amorphous) near10 resistivity	USPAT	2004/07/12 10:38
-	14	349/113 and (conduct\$4 near10 amorphous)	USPAT	2004/07/12 11:02
-	2	(conduct\$4 adj amorphous)near10 resistivity	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/13 12:12
-	4901	passivation near10 conduct\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/13 12:15
-	44	(passivation near10 conduct\$4) near10 (amorphous or diamon-like)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/13 15:50
-	9	(passivation near10 conduct\$4) near10 (amorphous or diamon-like) and (orientation or alignment)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/13 16:34
-	0	(passivation near10 conduct\$4) near10 (amorphous or diamon-like) near10 (orientation or alignment)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/13 16:34

-	2186	(amorphous or diamon-like) near10 (orientation or alignment)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/13 16:35
-	4	conduct\$4 near0 (amorphous or diamon-like) near10 (orientation or alignment)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/13 16:35
-	30	((part\$4 or conduct\$4) near10 amorphous near10 resistivity) and (liquid adj crystal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/16 10:08
-	6	((part\$4 or conduct\$4) near10 amorphous near10 resistivity) and (liquid adj crystal) and (passiva\$4 or protect\$4) and align\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/16 09:45
-	0	((passiva\$4 protect\$4)near10 electrode near10 (liquid adj crystal)) and (conduct\$4 near10 amorphous near10 aligh\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/16 10:13
-	1472	((passiva\$4 protect\$4)near10 electrode near10 (liquid adj crystal))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/16 10:12
-	42	((passiva\$4 protect\$4)near10 electrode near10 (liquid adj crystal)) and (conduct\$4 near10 amorphous)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/16 12:28
-	2	6344888.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/07/16 10:35